

NCE N-Channel Enhancement Mode Power MOSFET

Description

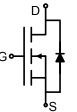
The NCE3420 uses advanced trench technology to provide excellent $R_{DS(ON)}$, low gate charge and operation with gate voltages as low as 1.8V. This device is suitable for use as a uni-directional or bi-directional load switch.

General Features

- V_{DS} = 20V,I_D = 6A
 - $$\begin{split} &R_{DS(ON)} < 35 m\Omega @V_{GS} = 2.5 V \\ &R_{DS(ON)} < 28 m\Omega @V_{GS} = 4.5 V \end{split}$$
- High Power and current handing capability
- Lead free product is acquired
- Surface Mount Package

Application

- Uni-directional Load switch
- Bi-directional Load switch



Schematic diagram



Marking and pin Assignment



Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
3420	NCE3420	SOT-23	Ø180mm	8 mm	3000 units

Absolute Maximum Ratings (T_A=25℃ unless otherwise noted)

Parameter	Symbol	Limit	Unit	
Drain-Source Voltage	Vds	20	V	
Gate-Source Voltage	Vgs	±10	V	
Drain Current-Continuous	I _D	6	A	
Drain Current-Pulsed (Note 1)	I _{DM}	30	A	
Maximum Power Dissipation	PD	1.25	W	
Operating Junction and Storage Temperature Range	T _J ,T _{STG}	-55 To 150	°C	

Thermal Characteristic

Thermal Resistance, Junction-to-Ambient (Note 2)	R _{eJA}	100	°C /W
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Electrical Characteristics (T_A=25[°]C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =250µA	20	22	-	V
Zero Gate Voltage Drain Current	I _{DSS}	V_{DS} =20V, V_{GS} =0V	-	-	1	μA





Gate-Body Leakage Current	I _{GSS}	V_{GS} =±10V, V_{DS} =0V	-	-	±100	nA
On Characteristics (Note 3)					L	
Gate Threshold Voltage	V _{GS(th)}	$V_{DS}=V_{GS}$, $I_{D}=250\mu A$	0.5	0.7	1.0	V
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =2.5V, I _D =4.0 A	-	27	35	mΩ
Drain-Source On-State Resistance		V _{GS} =4.5V, I _D =5.0A	-	20	28	mΩ
Forward Transconductance	g fs	V _{DS} =5V,I _D =6A	-	25	-	S
Dynamic Characteristics (Note4)						
Input Capacitance	C _{lss}		-	515	-	PF
Output Capacitance	Coss	- V _{DS} =10V,V _{GS} =0V, - F=1.0MHz	-	90	-	PF
Reverse Transfer Capacitance	Crss		-	72	-	PF
Switching Characteristics (Note 4)	·			•		
Turn-on Delay Time	t _{d(on)}		-	3	-	nS
Turn-on Rise Time	tr	V_{DD} =10V, R _L =1.7 Ω	-	7.5	-	nS
Turn-Off Delay Time	t _{d(off)}	V_{GS} =10V, R_{GEN} =3 Ω	-	20	-	nS
Turn-Off Fall Time	t _f		-	6	-	nS
Total Gate Charge	Qg		-	12	-	nC
Gate-Source Charge	Q _{gs}	V _{DS} =10V,I _D =6A,V _{GS} =10V	-	1	-	nC
Gate-Drain Charge	Q _{gd}		-	2	-	nC
Drain-Source Diode Characteristics	·				-	
Diode Forward Voltage (Note 3)	V _{SD}	V _{GS} =0V,I _S =1A	-	-	1.2	V
Diode Forward Current (Note 2)	I _S		-	-	6	А

Notes:

1. Repetitive Rating: Pulse width limited by maximum junction temperature.

2. Surface Mounted on FR4 Board, $t \le 10$ sec.

3. Pulse Test: Pulse Width \leq 300µs, Duty Cycle \leq 2%.

4. Guaranteed by design, not subject to production



NCE3420



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Typical Electrical and Thermal Characteristics

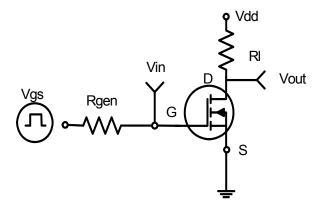
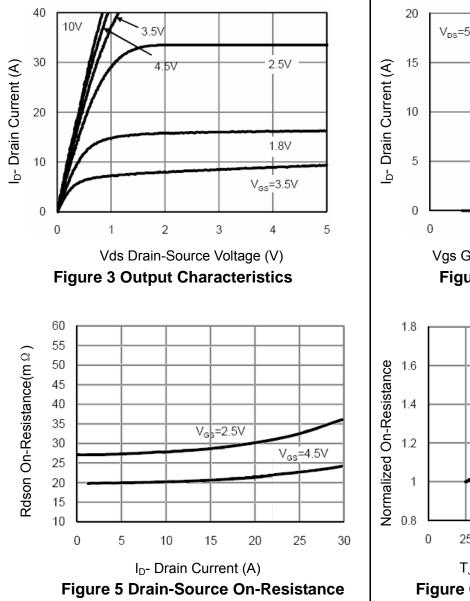
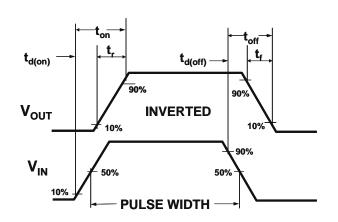


Figure 1:Switching Test Circuit







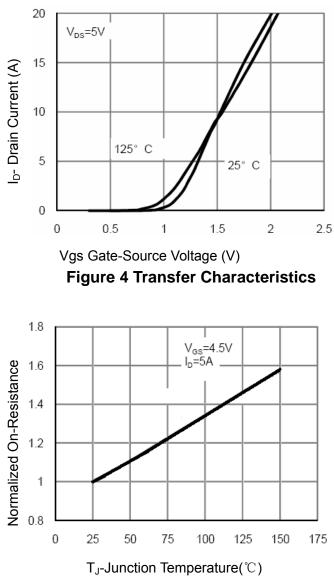
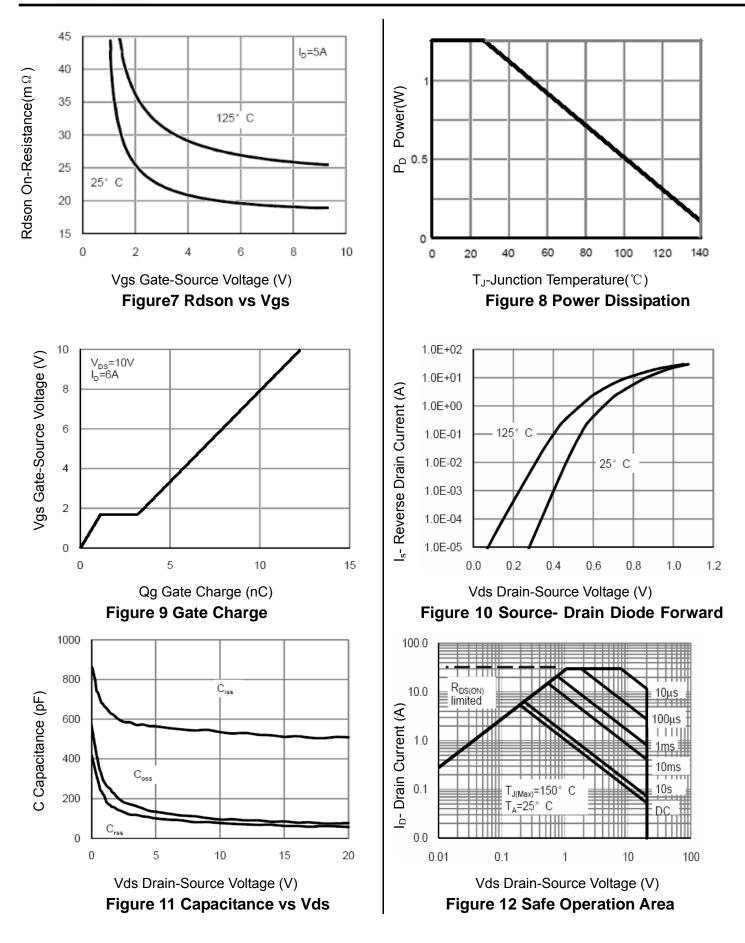


Figure 6 Drain-Source On-Resistance



Pb Free Product

NCE3420









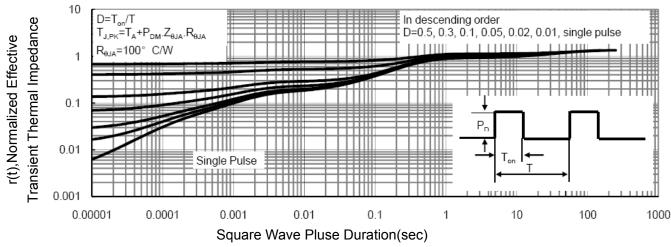
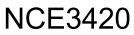
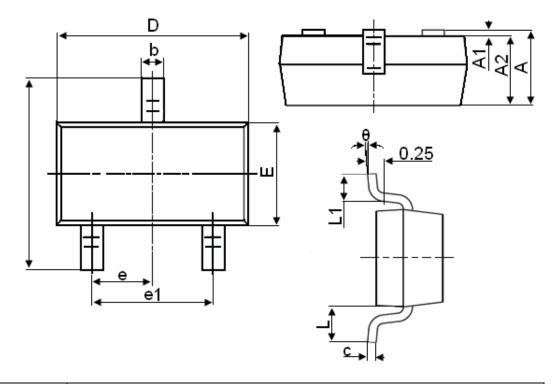


Figure 13 Normalized Maximum Transient Thermal Impedance





SOT-23 Package Information



Symbol		Dimensions in Millimeters		
Symbol	MIN.	MAX.		
А	0.900	1.150		
A1	0.000	0.100		
A2	0.900	1.050		
b	0.300	0.500		
с	0.080	0.150		
D	2.800	3.000		
E	1.200	1.400		
E1	2.250	2.550		
е		0.950TYP		
e1	1.800	2.000		
L		0.550REF		
L1	0.300	0.500		
θ	0°	8°		

Notes

- 1. All dimensions are in millimeters.
- 2. Tolerance ±0.10mm (4 mil) unless otherwise specified
- 3. Package body sizes exclude mold flash and gate burrs. Mold flash at the non-lead sides should be less than 5 mils.
- 4. Dimension L is measured in gauge plane.
- 5. Controlling dimension is millimeter, converted inch dimensions are not necessarily exact.







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